imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



12 V, 7.0 A, Low V_{CE(sat)} **NPN Transistor**

ON Semiconductor's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

• This is a Pb-Free Device

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	12	Vdc
Collector-Base Voltage	V _{CBO}	12	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current - Continuous	Ι _C	5.0	Adc
Collector Current - Peak	I _{CM}	7.0	А
Electrostatic Discharge	ESD	HBM Class 3B MM Class C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 1)	875 7.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	143	°C/W
Total Device Dissipation, $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D (Note 2)	1.5 11.8	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	85	°C/W
Thermal Resistance, Junction-to-Lead #1	$R_{\theta JL}$ (Note 2)	23	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

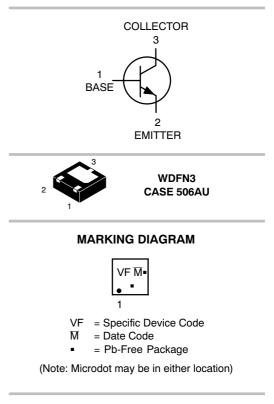
FR-4 @ 100 mm², 1 oz copper traces.
FR-4 @ 500 mm², 1 oz copper traces.



ON Semiconductor®

http://onsemi.com

12 VOLTS, 7.0 AMPS NPN LOW V_{CE(sat)} TRANSISTOR EQUIVALENT $\hat{R}_{DS(on)}$ 31 m Ω



ORDERING INFORMATION

Device	Package	Shipping [†]	
NSS12501UW3T2G	WDFN3 (Pb-Free)	3000/ Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS			•	•	•
Collector-Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	12	-	-	Vdc
Collector-Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$	V _{(BR)CBO}	12	-	-	Vdc
Emitter-Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	V _{(BR)EBO}	6.0	-	-	Vdc
Collector Cutoff Current ($V_{CB} = 12 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	-	0.1	μAdc
Emitter Cutoff Current (V _{EB} = 6.0 Vdc)	I _{EBO}	-	-	0.1	μAdc
ON CHARACTERISTICS				•	•
$ \begin{array}{l} \text{DC Current Gain (Note 3)} \\ (I_{C} = 10 \text{ mA}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 3.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \\ (I_{C} = 3.0 \text{ A}, V_{CE} = 2.0 \text{ V}) \end{array} $	h _{FE}	200 200 200 200 200	- 345 330 315	- - - - -	
	V _{CE(sat)}	- - - - -	0.007 0.031 0.045 0.070 0.100 0.100	0.008 0.035 0.060 0.100 0.120 0.120	V
Base-Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ A}, I_B = 0.01 \text{ A})$	V _{BE(sat)}	-	0.760	0.900	V
Base-Emitter Turn-on Voltage (Note 3) $(I_C = 2.0 \text{ A}, V_{CE} = 2.0 \text{ V})$	V _{BE(on)}	-	0.730	0.900	V
Cutoff Frequency (I _C = 100 mA, V _{CE} = 5.0 V, f = 100 MHz)	f _T	150	-	-	MHz
Input Capacitance (V _{EB} = 0.5 V, f = 1.0 MHz)	Cibo	-		650	pF
Output Capacitance (V _{CB} = 3.0 V, f = 1.0 MHz)	Cobo	-		120	pF
SWITCHING CHARACTERISTICS					
Delay (V _{CC} = 10 V, I_C = 750 mA, I_{B1} = 15 mA)	t _d	-	-	90	ns
Rise (V _{CC} = 10 V, I _C = 750 mA, I _{B1} = 15 mA)	t _r	-	-	100	ns
Storage (V _{CC} = 10 V, I_C = 750 mA, I_{B1} = 15 mA)	t _s	-	-	320	ns
Fall (V _{CC} = 10 V, I _C = 750 mA, I _{B1} = 15 mA)	t _f	-	-	100	ns

3. Pulsed Condition: Pulse Width = 300 $\mu sec,$ Duty Cycle \leq 2%.

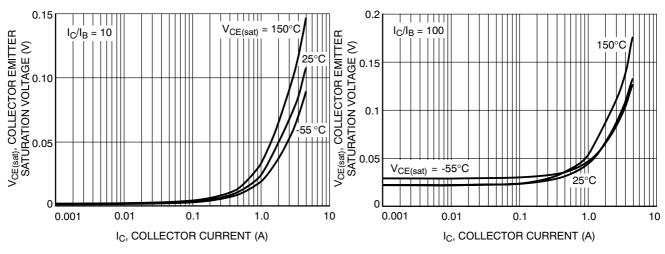


Figure 1. Collector Emitter Saturation Voltage vs. Collector Current

Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

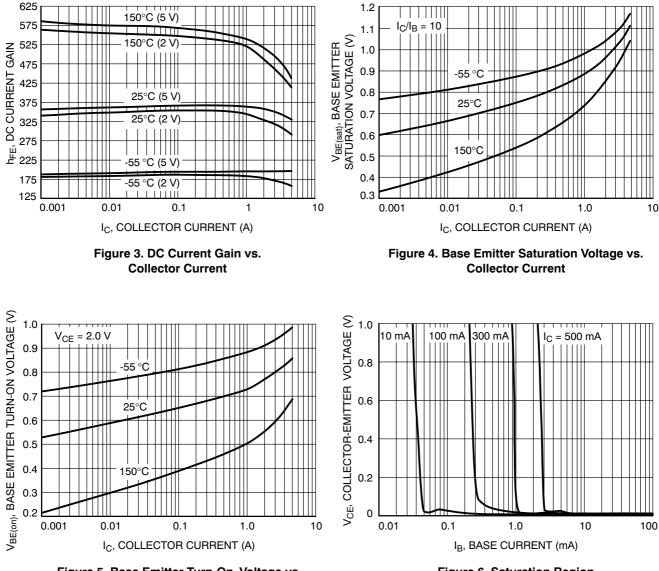


Figure 5. Base Emitter Turn-On Voltage vs. Collector Current

Figure 6. Saturation Region

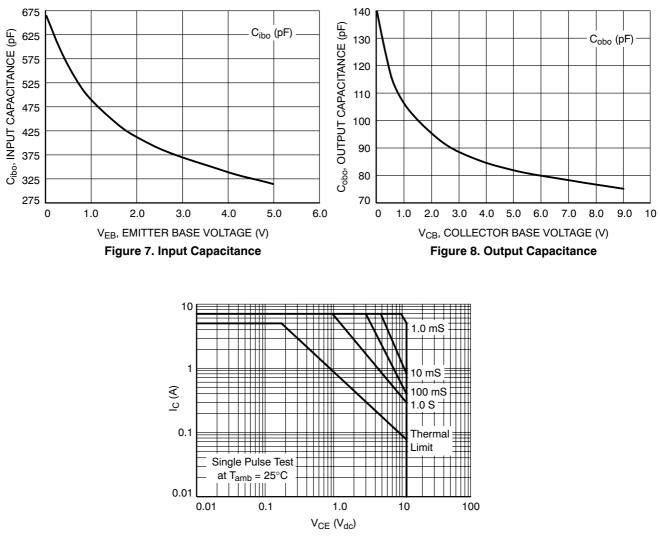
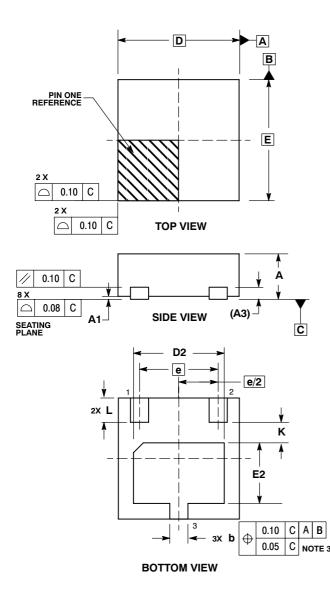


Figure 9. Safe Operating Area

PACKAGE DIMENSIONS

WDFN3 CASE 506AU-01 ISSUE O

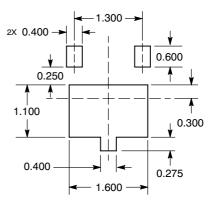


NOTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994 .
- 2. 3.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS 4 THE TERMINALS.

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00		0.05	0.000		0.002
A3	0.20 REF			0.008 REF		
b	0.25	0.30	0.35	0.010	0.012	0.014
D	2.00 BSC			0.079 BSC		
D2	1.40	1.50	1.60	0.055	0.059	0.063
E	2.00 BSC			0.079 BSC		
E2	0.90	1.00	1.10	0.035	0.039	0.043
е	1.30 BSC			0.051 BSC		
к	0.35 REF			0.014 REF		
L	0.35	0.40	0.45	0.014	0.016	0.018

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC observed any end to the provide and the part in the validated for each customer application by customer's technical experts. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications are specified for each customer applications and customer specifications and specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications are specified for each customer applications are specified for each customer's technical experts. SCILLC products are not designed, intended, or authorized for use a components in systems intended for surgical implant into the body, or other applications are provided in the followed for the specified for each customer applications are specified bit intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative